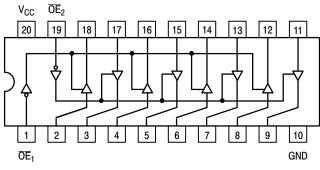
# **Octal Buffer/Line Driver** with 3-State Outputs

The MC74AC244/74ACT244 is an octal buffer and line driver designed to be employed as a memory address driver, clock driver and bus oriented transmitter/receiver which provides improved PC board density.

#### Features

- 3-State Outputs Drive Bus Lines or Buffer Memory Address Registers
- Outputs Source/Sink 24 mA
- 'ACT244 Has TTL Compatible Inputs
- These are Pb–Free Devices



Pinout: 20-Lead Packages Conductors (Top View)

#### TRUTH TABLE

Inp	uts	Outputs				
$\overline{OE}_1$	D	(Pins 12, 14, 16, 18)				
L	L	L				
L	н	Н				
н	Х	Z				
NOTE	NOTE: H = HIGH Voltage Level					
	L =	LOW Voltage Level				

X = Immaterial

Z = High Impedance

#### TRUTH TABLE

Inputs		Outputs
$\overline{OE}_2$	D	(Pins 3, 5, 7, 9)
L	L	L
L	Н	Н
Н	Х	Z

NOTE: H = HIGH Voltage Level L = LOW Voltage Level

X = Immaterial

Z = High Impedance



# **ON Semiconductor®**

www.onsemi.com



SOIC-20W DW SUFFIX CASE 751D



TSSOP-20 DT SUFFIX CASE 948E

### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

#### **DEVICE MARKING INFORMATION**

See general marking information in the device marking section on page 5 of this data sheet.

#### MAXIMUM RATINGS

Symbol	Param	eter	Value	Unit
V <sub>CC</sub>	DC Supply Voltage (Referenced to GND)		-0.5 to +7.0	V
V <sub>IN</sub>	DC Input Voltage (Referenced to GND)		–0.5 to V <sub>CC</sub> +0.5	V
V <sub>OUT</sub>	DC Output Voltage (Referenced to GND) (	Note 1)	–0.5 to V <sub>CC</sub> +0.5	V
I <sub>IK</sub>	DC Input Diode Current		±20	mA
I <sub>OK</sub>	DC Output Diode Current		±50	mA
I <sub>OUT</sub>	DC Output Sink/Source Current		±50	mA
I <sub>CC</sub>	DC Supply Current, per Output Pin		±50	mA
I <sub>GND</sub>	DC Ground Current, per Output Pin		±100	mA
T <sub>STG</sub>	Storage Temperature Range		-65 to +150	°C
ΤL	Lead temperature, 1 mm from Case for 10	Seconds	260	°C
TJ	Junction Temperature Under Bias		140	°C
$\theta_{JA}$	Thermal Resistance (Note 2)	SOIC TSSOP	65.8 110.7	°C/W
MSL	Moisture Sensitivity		Level 1	
F <sub>R</sub>	Flammability Rating	Oxygen Index: 30% – 35%	UL 94 V-0 @ 0.125 in	
V <sub>ESD</sub>	ESD Withstand Voltage	Human Body Model (Note 3) Machine Model (Note 4) Charged Device Model (Note 5)	> 2000 > 200 > 1000	V
I <sub>Latchup</sub>	Latchup Performance Abov	e V <sub>CC</sub> and Below GND at 85°C (Note 6)	±100	mA

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. I<sub>OUT</sub> absolute maximum rating must be observed.

2. The package thermal impedance is calculated in accordance with JESD 51-7.

3. Tested to EIA/JESD22-A114-A.

4. Tested to EIA/JESD22-A115-A.

Tested to JESD22-C101-A. 5.

6. Tested to EIA/JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Min	Тур	Max	Unit
M	Supply Voltage	′AC	2.0	5.0	6.0	v
V <sub>CC</sub>	Supply Voltage	'ACT	4.5	5.0	5.5	v
V <sub>IN</sub> , V <sub>OUT</sub>	DC Input Voltage, Output Voltage (Ref. to GND)		0	-	V <sub>CC</sub>	V
		V <sub>CC</sub> @ 3.0 V	-	150	-	ns/V
t <sub>r</sub> , t <sub>f</sub>	Input Rise and Fall Time (Note 7) 'AC Devices except Schmitt Inputs	V <sub>CC</sub> @ 4.5 V	-	40	-	
		V <sub>CC</sub> @ 5.5 V	-	25	-	
	Input Rise and Fall Time (Note 8)	V <sub>CC</sub> @ 4.5 V	-	10	-	20/
t <sub>r</sub> , t <sub>f</sub>	'ACT Devices except Schmitt Inputs	V <sub>CC</sub> @ 5.5 V	-	8.0	-	ns/V
T <sub>A</sub>	Operating Ambient Temperature Range		-40	25	85	°C
I <sub>OH</sub>	Output Current – High		-	-	-24	mA
I <sub>OL</sub>	Output Current – Low		_	-	24	mA

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

7.  $V_{IN}$  from 30% to 70%  $V_{CC}$ ; see individual Data Sheets for devices that differ from the typical input rise and fall times. 8.  $V_{IN}$  from 0.8 V to 2.0 V; see individual Data Sheets for devices that differ from the typical input rise and fall times.

#### **DC CHARACTERISTICS**

			74	AC	74AC			
Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C		T <sub>A</sub> = −40°C to +85°C	Unit	Conditions	
			Тур	Gua	ranteed Limits			
V <sub>IH</sub>	Minimum High Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	2.1 3.15 3.85	2.1 3.15 3.85	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$	
V <sub>IL</sub>	Maximum Low Level Input Voltage	3.0 4.5 5.5	1.5 2.25 2.75	0.9 1.35 1.65	0.9 1.35 1.65	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$	
V <sub>OH</sub>	Minimum High Level Output Voltage	3.0 4.5 5.5	2.99 4.49 5.49	2.9 4.4 5.4	2.9 4.4 5.4	V	I <sub>OUT</sub> = -50 μA	
		3.0 4.5 5.5	_ _ _	2.56 3.86 4.86	2.46 3.76 4.76	V	$\label{eq:VIN} \begin{array}{c} {}^{*}V_{IN} = V_{IL} \text{ or } V_{IH} \\ & -12 \text{ mA} \\ I_{OH} & -24 \text{ mA} \\ & -24 \text{ mA} \end{array}$	
V <sub>OL</sub>	Maximum Low Level Output Voltage	3.0 4.5 5.5	0.002 0.001 0.001	0.1 0.1 0.1	0.1 0.1 0.1	V	I <sub>OUT</sub> = 50 μA	
		3.0 4.5 5.5	_ _ _	0.36 0.36 0.36	0.44 0.44 0.44	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ $12 \text{ mA}$ $I_{OL}$ $24 \text{ mA}$ $24 \text{ mA}$	
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	_	±0.1	±1.0	μΑ	$V_{I} = V_{CC}, GND$	
I <sub>OZ</sub>	Maximum 3–State Current	5.5	-	±0.5	±5.0	μΑ		
I <sub>OLD</sub>	†Minimum Dynamic Output Current	5.5	-	-	75	mA	V <sub>OLD</sub> = 1.65 V Max	
I <sub>OHD</sub>	]	5.5	-	-	-75	mA	V <sub>OHD</sub> = 3.85 V Min	
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	_	8.0	80	μΑ	$V_{IN} = V_{CC}$ or GND	

\*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

NOTE:  $I_{IN}$  and  $I_{CC}$  @ 3.0 V are guaranteed to be less than or equal to the respective limit @ 5.5 V V<sub>CC</sub>.

AC CHARACTERISTICS (For Figures and Waveforms - See AND8277/D at www.onsemi.com)

				74AC		74	AC		
Symbol	Parameter	V <sub>CC</sub> * (V)		$T_A = +25^{\circ}C$ $C_L = 50 \text{ pF}$		$T_{A} = -40^{\circ}C_{L} = 0$	C to +85°C 50 pF	Unit	Figure No.
			Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay Data to Output	3.3 5.0	2.0 1.5	6.5 5.0	9.0 7.0	1.5 1.0	10.0 7.5	ns	3–5
t <sub>PHL</sub>	Propagation Delay Data to Output	3.3 5.0	2.0 1.5	6.5 5.0	9.0 7.0	2.0 1.0	10.0 7.5	ns	3–5
t <sub>PZH</sub>	Output Enable Time	3.3 5.0	2.0 1.5	6.0 5.0	10.5 7.0	1.5 1.5	11.0 8.0	ns	3–7
t <sub>PZL</sub>	Output Enable Time	3.3 5.0	2.5 1.5	7.5 5.5	10.0 8.0	2.0 1.5	11.0 8.5	ns	3–8
t <sub>PHZ</sub>	Output Disable Time	3.3 5.0	3.0 2.5	7.0 6.5	10.0 9.0	1.5 1.0	10.5 9.5	ns	3–7
t <sub>PLZ</sub>	Output Disable Time	3.3 5.0	2.5 2.0	7.5 6.5	10.5 9.0	2.5 2.0	11.5 9.5	ns	3–8

\*Voltage Range 3.3 V is 3.3 V  $\pm 0.3$  V. \*Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

#### **DC CHARACTERISTICS**

			74 <i>A</i>	СТ	74ACT			
Symbol	Parameter	V <sub>CC</sub> (V)	T <sub>A</sub> = +25°C		T <sub>A</sub> = −40°C to +85°C	Unit	Conditions	
			Typ Gua		ranteed Limits			
V <sub>IH</sub>	Minimum High Level Input Voltage	4.5 5.5	1.5 1.5	2.0 2.0	2.0 2.0	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$	
V <sub>IL</sub>	Maximum Low Level Input Voltage	4.5 5.5	1.5 1.5	0.8 0.8	0.8 0.8	V	$V_{OUT} = 0.1 V$ or $V_{CC} - 0.1 V$	
V <sub>OH</sub>	Minimum High Level Output Voltage	4.5 5.5	4.49 5.49	4.4 5.4	4.4 5.4	V	I <sub>OUT</sub> = -50 μA	
		4.5 5.5		3.86 4.86	3.76 4.76	V	$\label{eq:VIN} \begin{array}{c} {}^{*}V_{IN} = V_{IL} \text{ or } V_{IH} \\ -24 \text{ mA} \\ I_{OH} -24 \text{ mA} \end{array}$	
V <sub>OL</sub>	Maximum Low Level Output Voltage	4.5 5.5	0.001 0.001	0.1 0.1	0.1 0.1	V	I <sub>OUT</sub> = 50 μA	
		4.5 5.5		0.36 0.36	0.44 0.44	V	$V_{IN} = V_{IL} \text{ or } V_{IH}$ 24 mA $V_{OL}$ 24 mA	
I <sub>IN</sub>	Maximum Input Leakage Current	5.5	-	±0.1	±1.0	μΑ	$V_{I} = V_{CC}, GND$	
$\Delta I_{CCT}$	Additional Max. I <sub>CC</sub> /Input	5.5	0.6	-	1.5	mA	$V_{I} = V_{CC} - 2.1 V$	
I <sub>OZ</sub>	Maximum 3–State Current	5.5	-	±0.5	±5.0	μΑ		
I <sub>OLD</sub>	†Minimum Dynamic Output Current	5.5	-	-	75	mA	V <sub>OLD</sub> = 1.65 V Max	
I <sub>OHD</sub>	1	5.5	-	-	-75	mA	V <sub>OHD</sub> = 3.85 V Min	
I <sub>CC</sub>	Maximum Quiescent Supply Current	5.5	_	8.0	80	μΑ	$V_{IN} = V_{CC}$ or GND	

\*All outputs loaded; thresholds on input associated with output under test. †Maximum test duration 2.0 ms, one output loaded at a time.

#### AC CHARACTERISTICS (For Figures and Waveforms - See AND8277/D at www.onsemi.com)

				74ACT		744	СТ		
Symbol	Parameter	V <sub>CC</sub> * (V)		$T_A = +25^{\circ}C$ $C_L = 50 \text{ pF}$		T <sub>A</sub> = -40°C C <sub>L</sub> =	C to +85°C 50 pF	Unit	Figure No.
			Min	Тур	Max	Min	Max		
t <sub>PLH</sub>	Propagation Delay Data to Output	5.0	2.0	6.5	9.0	1.5	10.0	ns	3–5
t <sub>PHL</sub>	Propagation Delay Data to Output	5.0	2.0	7.0	9.0	1.5	10.0	ns	3–5
t <sub>PZH</sub>	Output Enable Time	5.0	1.5	6.0	8.5	1.0	9.5	ns	3–7
t <sub>PZL</sub>	Output Enable Time	5.0	2.0	7.0	9.5	1.5	10.5	ns	3–8
t <sub>PHZ</sub>	Output Disable Time	5.0	2.0	7.0	9.5	1.5	10.5	ns	3–7
t <sub>PLZ</sub>	Output Disable Time	5.0	2.5	7.5	10.0	2.0	10.5	ns	3–8

\*Voltage Range 5.0 V is 5.0 V  $\pm 0.5$  V.

#### CAPACITANCE

Symbol	Parameter	Value Typ	Unit	Test Conditions
C <sub>IN</sub>	Input Capacitance	4.5	pF	V <sub>CC</sub> = 5.0 V
C <sub>PD</sub>	Power Dissipation Capacitance	45	pF	$V_{CC} = 5.0 V$

#### **ORDERING INFORMATION**

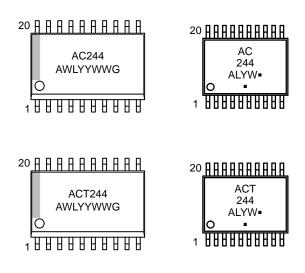
Device	Package	Shipping <sup>†</sup>
MC74AC244DWG		38 Units / Rail
MC74AC244DWR2G	SOIC-20	1000 / Tape & Reel
MC74ACT244DWG	(Pb-Free)	38 Units / Rail
MC74ACT244DWR2G	-	1000 / Tape & Reel
MC74AC244DTR2G	TSSOP-20	2500 / Tape & Reel
MC74ACT244DTR2G	(Pb-Free)	2500 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

#### MARKING DIAGRAMS

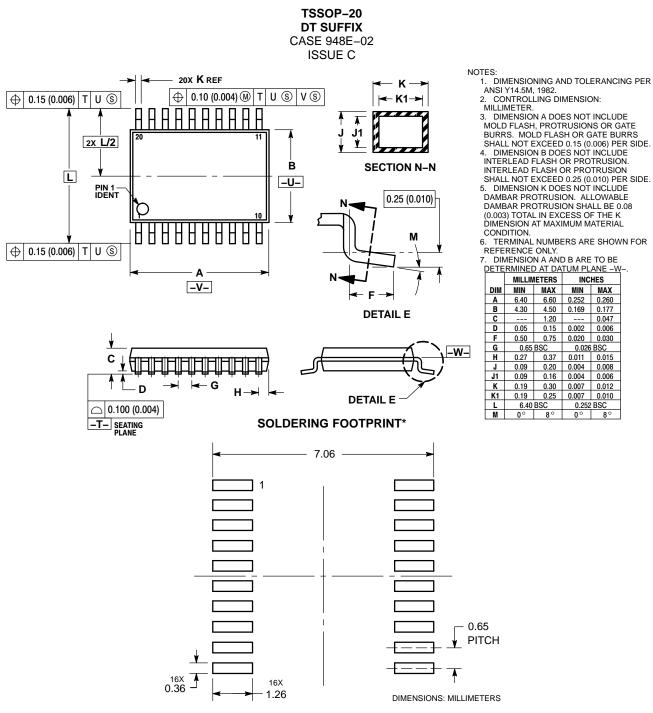
SOIC-20W

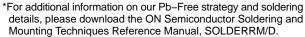
TSSOP-20

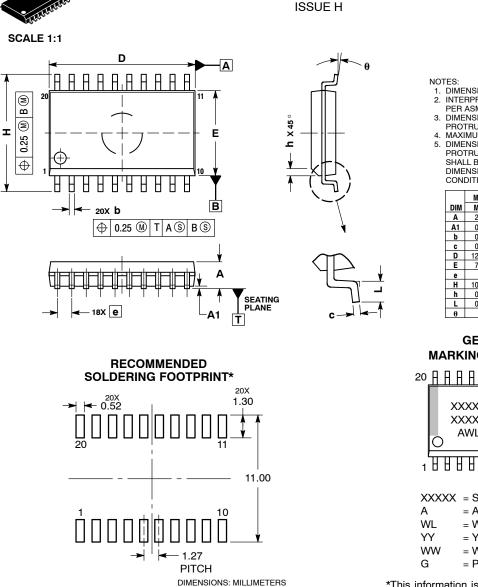


А	= Assembly Location
WL, L	= Wafer Lot
YY, Y	= Year
WW, W	= Work Week
G or ■	= Pb-Free Package
(Note: Microd	ot may be in either location)

#### PACKAGE DIMENSIONS







SOIC-20 WB CASE 751D-05

\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

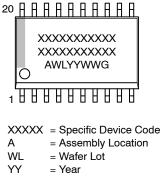
DATE 22 APR 2015

DUSEM

- 1. DIMENSIONS ARE IN MILLIMETERS. 2. INTERPRET DIMENSIONS AND TOLERANCES
- PER ASME Y14.5M, 1994. 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
- DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS						
DIM	MIN	MAX					
Α	2.35	2.65					
A1	0.10	0.25					
b	0.35	0.49					
C	0.23	0.32					
D	12.65	12.95					
E	7.40	7.60					
е	1.27	BSC					
н	10.05	10.55					
h	0.25	0.75					
L	0.50	0.90					
θ	0 °	7 °					

GENERIC **MARKING DIAGRAM\*** 



- = Work Week
- = Pb-Free Package

\*This information is generic. Please refer to device data sheet for actual part marking. Pb–Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

DOCUMENT NUMBER:	98ASB42343B	SB42343B         Electronic versions are uncontrolled except when accessed directly from the Document Repository.           Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.	
DESCRIPTION:	SOIC-20 WB PA		PAGE 1 OF 1
onsemi and ONSEMI are trademarks of Semiconductor Components Industries, LLC dba onsemi or its subsidiaries in the United States and/or other countries. onsemi reserves the right to make changes without further notice to any products herein. onsemi makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. onsemi does not convey any license under its patent rights nor the rights of others.			

onsemi, ONSEMI, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "onsemi" or its affiliates and/or subsidiaries in the United States and/or other countries. onsemi owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of onsemi's product/patent coverage may be accessed at <u>www.onsemi.com/site/pdf/Patent-Marking.pdf</u>. onsemi reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and onsemi makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does onsemi assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or indental damages. Buyer is responsible for its products and applications using onsemi products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by onsemi. "Typical" parameters which may be provided in onsemi data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. onsemi does not convey any license under any of its intellectual property rights nor the rights of others. onsemi products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification. Buyer shall indemnify and hold onsemi and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs,

#### ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:

Technical Library: www.onsemi.com/design/resources/technical-documentation onsemi Website: www.onsemi.com ONLINE SUPPORT: <u>www.onsemi.com/support</u> For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales